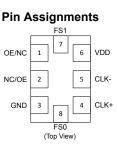


# Ultra Series<sup>™</sup> Crystal Oscillator Si562 Data Sheet

# Ultra Low Jitter Quad Any-Frequency XO (90 fs), 0.2 to 3000 MHz

The Si562 Ultra Series<sup>™</sup> oscillator utilizes Silicon Laboratories' advanced 4<sup>th</sup> generation DSPLL<sup>®</sup> technology to provide an ultra-low jitter, low phase noise clock at four selectable frequencies. The device is factory-programmed to provide any four selectable frequencies from 0.2 to 3000 MHz with <1 ppb resolution and maintains exceptionally low jitter for both integer and fractional frequencies across its operating range. The Si562 offers excellent reliability and frequency stability as well as guaranteed aging performance. On-chip power supply filtering provides industry-leading power supply noise rejection, simplifying the task of generating low jitter clocks in noisy systems that use switched-mode power supplies. Offered in industry-standard 3.2x5 mm and 5x7 mm footprints, the Si562 has a dramatically simplified supply chain that enables Silicon Labs to ship custom frequency samples 1-2 weeks after receipt of order. Unlike a traditional XO, where a different crystal is required for each output frequency, the Si562 uses one simple crystal and a DSPLL IC-based approach to provide the desired output frequencies. This process also guarantees 100% electrical testing of every device. The Si562 is factory-configurable for a wide variety of user specifications, including frequency, output format, and OE pin location/polarity. Specific configurations are factory-programmed at time of shipment, eliminating the long lead times associated with custom oscillators.





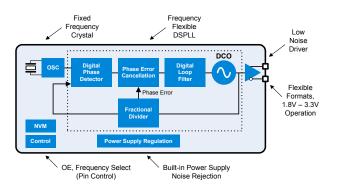
Pin #	Descriptions
1, 2	Selectable via ordering option OE = Output enable; NC = No Connect
3	GND = Ground
4	CLK+ = Clock output
5	CLK- = Complementary clock output. Not used for CMOS.
6	VDD = Power supply
7	FS1 = Frequency Select 1
8	FS0 = Frequency Select 0

#### KEY FEATURES

- Available with any four selectable frequencies from 200 kHz to 3000 MHz
- Ultra low jitter: 90 fs RMS typical (12 kHz 20 MHz)
- Excellent PSRR and supply noise immunity: –80 dBc Typ
- 20 ppm temp stability (-40 to 85 °C)
- 3.3 V, 2.5 V and 1.8 V V<sub>DD</sub> supply operation from the same part number
- LVPECL, LVDS, CML, HCSL, CMOS, and Dual CMOS output options
- · 3.2x5, 5x7 mm package footprints
- · Samples available with 1-2 week lead times

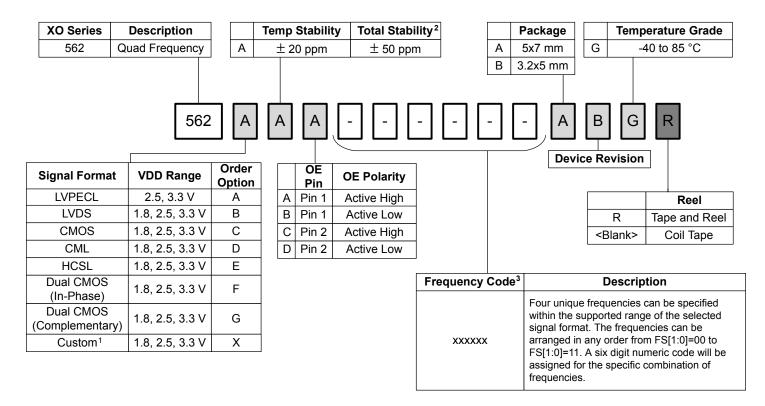
#### APPLICATIONS

- · 100G/200G/400G OTN, coherent optics
- 10G/25G/40G/100G Ethernet
- · 3G-SDI/12G-SDI/24G-SDI broadcast video
- Servers, switches, storage, NICs, search acceleration
- Test and measurement
- Clock and data recovery
- FPGA/ASIC clocking



## 1. Ordering Guide

The Si562 XO supports a variety of options including frequency, output format, and OE pin location/polarity, as shown in the chart below. Specific device configurations are programmed into the part at time of shipment, and samples are available in 1-2 weeks. Silicon Laboratories provides an online part number configuration utility to simplify this process. Refer to www.silabs.com/oscillators to access this tool and for further ordering instructions.



#### Notes:

- 1. Contact Silicon Labs for non-standard configurations.
- 2. Total stability includes temp stability, initial accuracy, load pulling, VDD variation, and 20 year aging at 70 °C.
- 3. Create custom part numbers at www.silabs.com/oscillators.

#### 1.1 Technical Support

Frequently Asked Questions (FAQ)	www.silabs.com/Si562-FAQ
Oscillator Phase Noise Lookup Utility	www.silabs.com/oscillator-phase-noise-lookup
Quality and Reliability	www.silabs.com/quality
Development Kits	www.silabs.com/oscillator-tools

## 2. Electrical Specifications

## Table 2.1. Electrical Specifications

 $V_{DD}$  = 1.8 V, 2.5 or 3.3 V  $\pm$  5%,  $T_A$  = –40 to 85 °C

Parameter	Symbol	Test Condition/Comment	Min	Тур	Max	Unit
Temperature Range	T <sub>A</sub>		-40	—	85	°C
Frequency Range	F <sub>CLK</sub>	LVPECL, LVDS, CML		_	3000	MHz
		HCSL	0.2	_	400	MHz
		CMOS, Dual CMOS	0.2		250	MHz
Supply Voltage	V <sub>DD</sub>	3.3 V	3.135	3.3	3.465	V
		2.5 V	2.375	2.5	2.625	V
		1.8 V	1.71	1.8	1.89	V
Supply Current	I <sub>DD</sub>	LVPECL (output enabled)	—	110	160	mA
		LVDS/CML (output enabled)	—	90	157	mA
		HCSL (output enabled)	—	85	130	mA
		CMOS (output enabled)	—	85	135	mA
		Dual CMOS (output enabled)	—	95	145	mA
		Tristate Hi-Z (output disabled)	—	73	_	mA
Temperature Stability		Frequency stability Grade A	-20	—	20	ppm
Total Stability <sup>1</sup>	F <sub>STAB</sub>	Frequency stability Grade A	-50	—	50	ppm
Rise/Fall Time	T <sub>R</sub> /T <sub>F</sub>	LVPECL/LVDS/CML	—	_	350	ps
(20% to 80% V <sub>PP</sub> )		CMOS / Dual CMOS (C <sub>L</sub> = 5 pF)	_	0.5	1.5	ns
		HCSL, F <sub>CLK</sub> >50 MHz	—	_	550	ps
Duty Cycle	D <sub>C</sub>	All formats	45	_	55	%
Output Enable (OE)	V <sub>IH</sub>		0.7 × V <sub>DD</sub>	_		V
Frequency Select (FS0, FS1) <sup>2</sup>	V <sub>IL</sub>		_	_	0.3 × V <sub>DD</sub>	V
	T <sub>D</sub>	Output Disable Time, F <sub>CLK</sub> > 10 MHz	_		3	μs
	TE	Output Enable Time, F <sub>CLK</sub> > 10 MHz	_	_	20	μs
	T <sub>FS</sub>	Settling Time after FS Change	_	_	10	ms
Powerup Time	tosc	Time from 0.9 × V <sub>DD</sub> until output fre- quency (F <sub>CLK</sub> ) within spec	-	_	10	ms
LVPECL Output Option <sup>3</sup>	V <sub>OC</sub>	Mid-level	V <sub>DD</sub> – 1.42	_	V <sub>DD</sub> – 1.25	V
	Vo	Swing (diff, F <sub>CLK</sub> ≤ 1.5 GHz)	1.1	_	1.9	V <sub>PP</sub>
		Swing (diff, F <sub>CLK</sub> > 1.5 GHz) <sup>6</sup>	0.55	_	1.7	V <sub>PP</sub>

Parameter	Symbol	Test Condition/Comment	Min	Тур	Max	Unit
LVDS Output Option <sup>4</sup>	V <sub>OC</sub>	Mid-level (2.5 V, 3.3 V VDD)	1.125	1.20	1.275	V
		Mid-level (1.8 V VDD)	0.8	0.9	1.0	V
	Vo	Swing (diff, F <sub>CLK</sub> ≤ 1.5 GHz)	0.5	0.7	0.9	V <sub>PP</sub>
		Swing (diff, F <sub>CLK</sub> > 1.5 GHz) <sup>6</sup>	0.25	0.5	0.8	V <sub>PP</sub>
HCSL Output Option <sup>5</sup>	V <sub>OH</sub>	H Output voltage high		800	850	mV
	V <sub>OL</sub>	Output voltage low	-150	0	150	mV
	V <sub>C</sub>	Crossing voltage	250	410	550	mV
CML Output Option (AC-Coupled)	Vo	Swing (diff, F <sub>CLK</sub> ≤ 1.5 GHz)	0.6	0.8	1.0	V <sub>PP</sub>
		Swing (diff, F <sub>CLK</sub> > 1.5 GHz) <sup>6</sup>	0.3	0.55	0.9	V <sub>PP</sub>
CMOS Output Option V <sub>OH</sub>		I <sub>OH</sub> = 8/6/4 mA for 3.3/2.5/1.8 V VDD	$0.85 \times V_{DD}$	—	—	V
	V <sub>OL</sub>	I <sub>OL</sub> = 8/6/4 mA for 3.3/2.5/1.8 V VDD	—	—	0.15 × V <sub>DD</sub>	V

## Notes:

1. Total Stability includes temperature stability, initial accuracy, load pulling, VDD variation, and aging for 20 yrs at 70 °C.

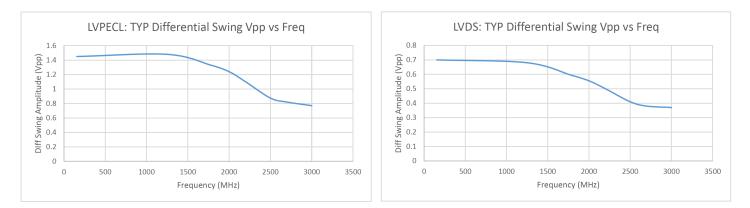
2. OE includes a 50 kΩ pull-up to VDD for OE active high, or includes a 50 kΩ pull-down to GND for OE active low. FS0 and FS1 pins each include a 50 kΩ pull-up to VDD. NC (No Connect) pins include a 50 kΩ pull-down to GND.

3. R<sub>term</sub> = 50  $\Omega$  to V<sub>DD</sub> – 2.0 V (see Figure 4.1).

4.  $R_{term}$  = 100  $\Omega$  (differential) (see Figure 4.2).

5. R<sub>term</sub> = 50  $\Omega$  to GND (see Figure 4.2).

6. Refer to the figure below for Typical Clock Output Swing Amplitudes vs Frequency.



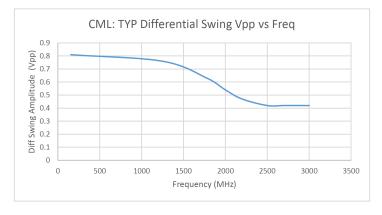


Figure 2.1. Typical Clock Output Swing Amplitudes vs. Frequency

## Table 2.2. Clock Output Phase Jitter and PSRR

## $V_{DD}$ = 1.8 V, 2.5 or 3.3 V $\pm$ 5%, $T_A$ = –40 to 85 °C

Parameter	Symbol	Test Condition/Comment	Min	Тур	Max	Unit
Phase Jitter (RMS, 12 kHz - 20 MHz) <sup>1</sup>	φJ	F <sub>CLK</sub> ≥ 200 MHz	_	90	140	fs
All Differential Formats		100 MHz ≤ F <sub>CLK</sub> < 200 MHz	_	105	160	fs
		LVPECL @ 156.25 MHz	_	95	125	fs
Phase Jitter (RMS, 12 kHz - 20 MHz) <sup>1</sup> CMOS / Dual CMOS Formats	φJ	¢J 10 MHz ≤ F <sub>CLK</sub> < 250 MHz		200	_	fs
Spurs Induced by External Power Supply	PSRR	100 kHz sine wave		-83		dBc
Noise, 50 mVpp Ripple. LVDS 156.25 MHz Output		200 kHz sine wave		-83		
		500 kHz sine wave		-82		
		1 MHz sine wave		-85		
Note: 1. Jitter inclusive of any spurs.	1		1	1	I	1

Table 2.3. 3.2 x 5 mm Clock Output Phase Noise (Typical)

Offset Frequency (f)	156.25 MHz LVDS	200 MHz LVDS	644.53125 MHz LVDS	Unit
100 Hz	–105	-100	-92	
1 kHz	–129	-126	–116	
10 kHz	-136	–133	-125	
100 kHz	-142	-140	–131	dBc/Hz
1 MHz	-150	-148	–138	
10 MHz	–159	–161	–153	
20 MHz	-160	-162	-154	
Offset Frequency (f)	156.25 MHz LVPECL	200 MHz LVPECL	644.53125 MHz LVPECL	Unit
100 Hz	–109	-102	-92	
1 kHz	–131	-126	–119	
10 kHz	–135	-134	-124	
100 kHz	-143	-141	–130	dBc/Hz
1 MHz	-150	-148	–138	
10 MHz	-160	-162	-154	
20 MHz	–161	-163	-155	

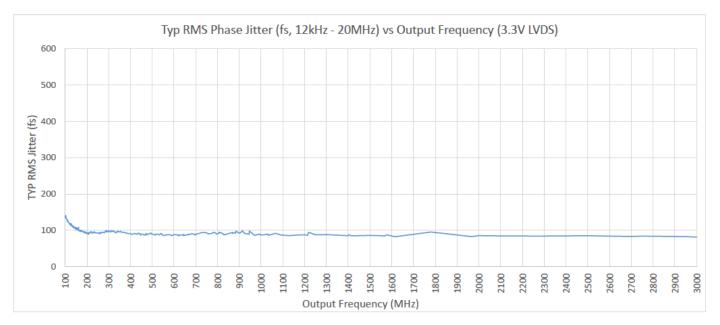


Figure 2.2. Phase Jitter vs. Output Frequency

Phase jitter measured with Agilent E5052 using a differential-to-single ended converter (balun or buffer). Measurements collected for >700 commonly used frequencies. Phase noise plots for specific frequencies are available using our free, online Oscillator Phase Noise Lookup Tool at www.silabs.com/oscillators.

#### Table 2.4. Environmental Compliance and Package Information

Parameter	Test Condition
Mechanical Shock	MIL-STD-883, Method 2002
Mechanical Vibration	MIL-STD-883, Method 2007
Solderability	MIL-STD-883, Method 2003
Gross and Fine Leak	MIL-STD-883, Method 1014
Resistance to Solder Heat	MIL-STD-883, Method 2036
Moisture Sensitivity Level (MSL)	1
Contact Pads	Gold over Nickel
Nata	

Note:

1. For additional product information not listed in the data sheet (e.g. RoHS Certifications, MDDS data, qualification data, REACH Declarations, ECCN codes, etc.), refer to our "Corporate Request For Information" portal found here: www.silabs.com/support/ quality/Pages/RoHSInformation.aspx.

#### Table 2.5. Thermal Conditions

Package	Parameter	Symbol	Test Condition	Value	Unit
	Thermal Resistance Junction to Ambient	Θ <sub>JA</sub>	Still Air, 85 °C	79.1	°C/W
3.2×5 mm 8-pin CLCC	Thermal Resistance Junction to Board	Θ <sub>JB</sub>	Still Air, 85 °C	49.6	°C/W
	Max Junction Temperature	TJ	Still Air, 85 °C	125	°C
	Thermal Resistance Junction to Ambient	Θ <sub>JA</sub>	Still Air, 85 °C	67.1	°C/W
5×7 mm 8-pin CLCC	Thermal Resistance Junction to Board	Θ <sub>JB</sub>	Still Air, 85 °C	51.7	°C/W
- F	Max Junction Temperature	TJ	Still Air, 85 °C	125	°C

## Table 2.6. Absolute Maximum Ratings<sup>1</sup>

Parameter	Symbol	Rating	Unit
Maximum Operating Temp.	T <sub>AMAX</sub>	95	°C
Storage Temperature	T <sub>S</sub>	–55 to 125	°C
Supply Voltage	V <sub>DD</sub>	–0.5 to 3.8	°C
Input Voltage	V <sub>IN</sub>	–0.5 to V <sub>DD</sub> + 0.3	V
ESD HBM (JESD22-A114)	НВМ	2.0	kV
Solder Temperature <sup>2</sup>	T <sub>PEAK</sub>	260	°C
Solder Time at T <sub>PEAK</sub> <sup>2</sup>	T <sub>P</sub>	20–40	sec

Notes:

1. Stresses beyond those listed in this table may cause permanent damage to the device. Functional operation specification compliance is not implied at these conditions. Exposure to maximum rating conditions for extended periods may affect device reliability.

2. The device is compliant with JEDEC J-STD-020.

## 3. Dual CMOS Buffer

Dual CMOS output format ordering options support either complementary or in-phase signals for two identical frequency outputs. This feature enables replacement of multiple XOs with a single Si562 device.

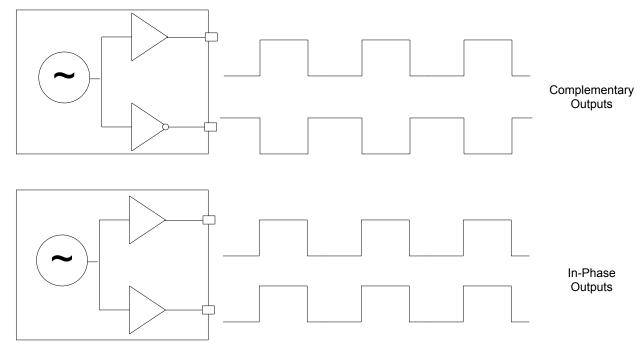


Figure 3.1. Integrated 1:2 CMOS Buffer Supports Complementary or In-Phase Outputs

## 4. Recommended Output Terminations

The output drivers support both AC-coupled and DC-coupled terminations as shown in figures below.

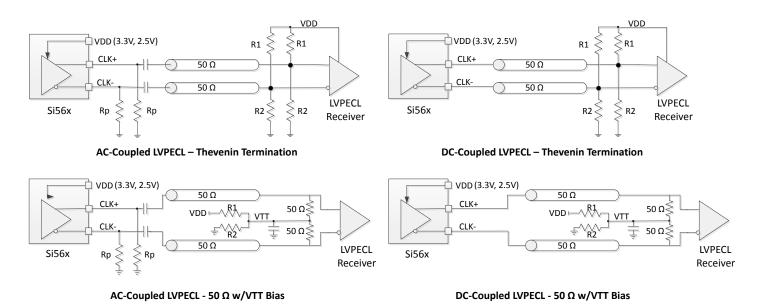
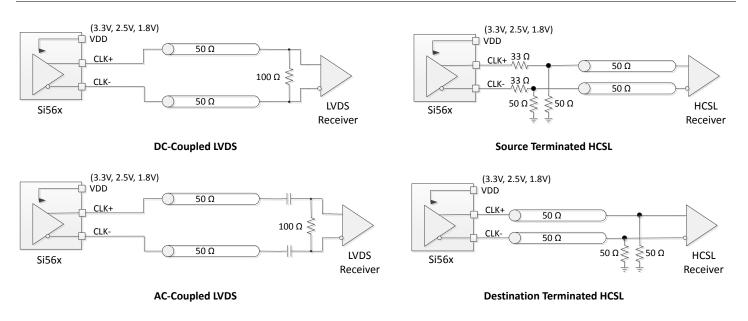


Figure 4.1. LVPECL Output Terminations

AC-Coupled LVPECL Termination Resistor Values					DC-Coupled LVPECL mination Resistor Va	
VDD	R1	R2	Rp	VDD	R1	R2
3.3 V	127 Ω	82.5 Ω	130 Ω	3.3 V	127 Ω	82.5 Ω
2.5 V	250 Ω	62.5 Ω	90 Ω	2.5 V	250 Ω	62.5 Ω





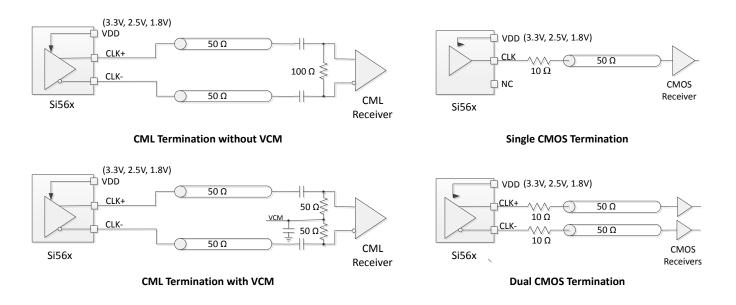
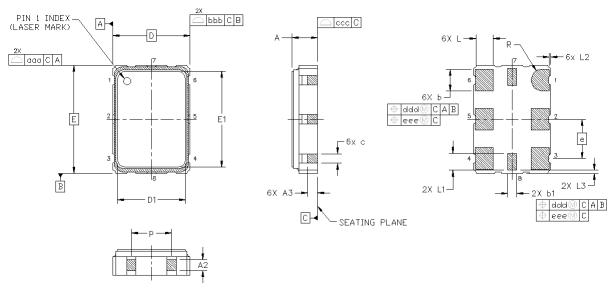


Figure 4.3. CML and CMOS Output Terminations

## 5. Package Outline

## 5.1 Package Outline (5x7 mm)

The figure below illustrates the package details for the 5x7 mm Si562. The table below lists the values for the dimensions shown in the illustration.



## Figure 5.1. Si562 (5x7 mm) Outline Diagram

Dimension	Min	Nom	Мах	Dimension	Min	Nom	Max
A	1.07	1.18	1.33	E1	6.10	6.20	6.30
A2	0.40	0.50	0.60	L	1.07	1.17	1.27
A3	0.45	0.55	0.65	L1	1.00	1.10	1.20
b	1.30	1.40	1.50	р	1.70		1.90
b1	0.50	0.60	0.70	R	0.70 REF		
С	0.50	0.60	0.70	aaa	0.15		
D		5.00 BSC		bbb		0.15	
D1	4.30	4.40	4.50	ссс	0.08		
е	2.54 BSC			ddd		0.10	
E		7.00 BSC		eee 0.05			
Notos:	1				1		

#### Table 5.1. Package Diagram Dimensions (mm)

#### Notes:

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

## 5.2 Package Outline (3.2x5 mm)

The figure below illustrates the package details for the 5x3.2 mm Si562. The table below lists the values for the dimensions shown in the illustration.

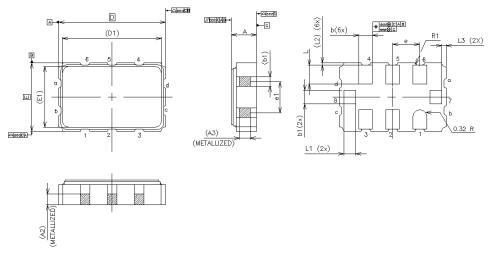


Figure 5.2. Si562 (3.2x5 mm) Outline Diagram

Table 5.2.	Package	Diagram	Dimensions	(mm)
------------	---------	---------	------------	------

Dimension	MIN	NOM	MAX		Dimension	MIN	NOM	MAX
A	1.02	1.17	1.33		E1	2.85 BSC		
A2	0.50	0.55	0.60		L	0.8	0.9	1.0
A3	0.45	0.50	0.55		L1	0.45	0.55	0.65
b	0.54	0.64	0.74		L2	0.05	0.10	0.15
b1	0.54	0.64	0.75		L3	0.15	0.20	0.25
D	5.00 BSC				aaa	0.15		
D1	4.65 BSC				bbb	0.15		
е	1.27 BSC				ccc	0.08		
e1	1.625 TYP				ddd	0.10		
E	3.20 BSC				eee	0.05		
Notes:								

1. All dimensions shown are in millimeters (mm) unless otherwise noted.

2. Dimensioning and Tolerancing per ANSI Y14.5M-1994.

## 6. PCB Land Pattern

## 6.1 PCB Land Pattern (5x7 mm)

The figure below illustrates the 5x7 mm PCB land pattern for the Si562. The table below lists the values for the dimensions shown in the illustration.

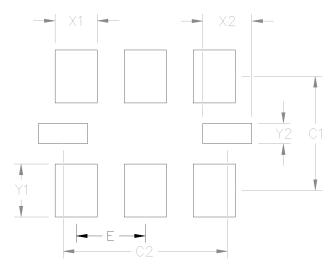


Figure 6.1. Si562 (5x7 mm) PCB Land Pattern

Table 6.1.	PCB Land	Pattern	Dimensions	(mm)
------------	----------	---------	------------	------

Dimension	(mm)	Dimension	(mm)
C1	4.20	Y1	1.95
C2	6.05	X2	1.80
E	2.54	Y2	0.75
X1	1.55		

Notes:

#### General

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
- 3. This Land Pattern Design is based on the IPC-7351 guidelines.
- 4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

## Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

## Stencil Design

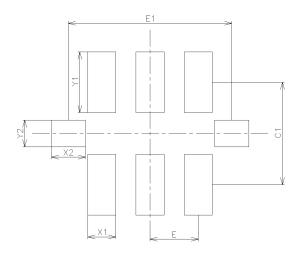
- 1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 2. The stencil thickness should be 0.125 mm (5 mils).
- 3. The ratio of stencil aperture to land pad size should be 1:1.

## Card Assembly

- 1. A No-Clean, Type-3 solder paste is recommended.
- 2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020D specification for Small Body Components.

## 6.2 PCB Land Pattern (3.2x5 mm)

The figure below illustrates the 3.2x5.0 mm PCB land pattern for the Si562. The table below lists the values for the dimensions shown in the illustration.





#### Table 6.2. PCB Land Pattern Dimensions (mm)

Dimension	(mm)	Dimension	(mm)
C1	2.70	X2	0.90
E	1.27	Y1	1.60
E1	4.30	Y2	0.70
X1	0.74		

#### Notes:

#### General

- 1. All dimensions shown are in millimeters (mm) unless otherwise noted.
- 2. Dimensioning and Tolerancing is per the ANSI Y14.5M-1994 specification.
- 3. This Land Pattern Design is based on the IPC-7351 guidelines.
- 4. All dimensions shown are at Maximum Material Condition (MMC). Least Material Condition (LMC) is calculated based on a Fabrication Allowance of 0.05 mm.

## Solder Mask Design

1. All metal pads are to be non-solder mask defined (NSMD). Clearance between the solder mask and the metal pad is to be 60 µm minimum, all the way around the pad.

### Stencil Design

- 1. A stainless steel, laser-cut and electro-polished stencil with trapezoidal walls should be used to assure good solder paste release.
- 2. The stencil thickness should be 0.125 mm (5 mils).
- 3. The ratio of stencil aperture to land pad size should be 1:1.

### **Card Assembly**

- 1. A No-Clean, Type-3 solder paste is recommended.
- 2. The recommended card reflow profile is per the JEDEC/IPC J-STD-020C specification for Small Body Components.

## 7. Top Marking

The figure below illustrates the mark specification for the Si562. The table below lists the line information.

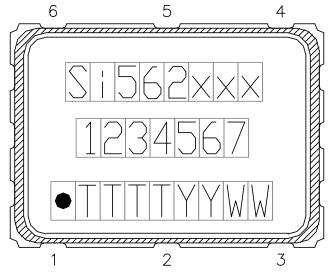


Figure 7.1. Mark Specification

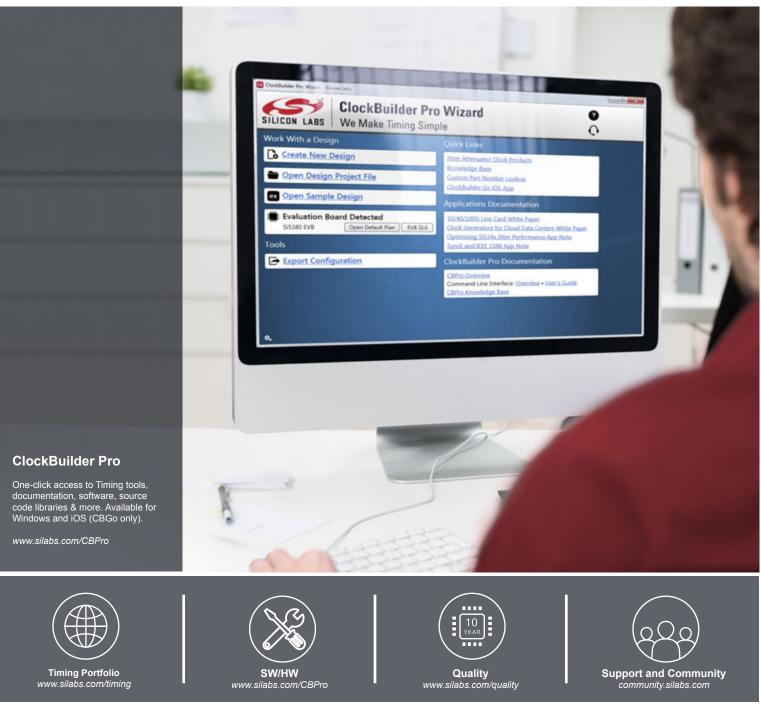
Line	Position	Description		
1	1–8	"Si562", xxx = Ordering Option 1, Option 2, Option 3 (e.g. Si562AAA)		
2	1–6	Frequency Code (6-digit custom code as described in the Ordering Guide)		
3		Trace Code		
	Position 1	Pin 1 orientation mark (dot)		
	Position 2	Product Revision (B)		
	Position 3–5	Tiny Trace Code (3 alphanumeric characters per assembly release instructions)		
	Position 6–7	Year (last two digits of the year), to be assigned by assembly site (ex: 2017 = 17)		
	Position 8–9	Calendar Work Week number (1–53), to be assigned by assembly site		

## 8. Revision History

## **Revision 1.0**

June, 2018

· Initial release.



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